# 35V Nch+Nch Power MOSFET

V <sub>DSS</sub>	35V
R <sub>DS(on)</sub> (Max.)	58mΩ
I <sub>D</sub>	±4.0A
P <sub>D</sub>	2.0W

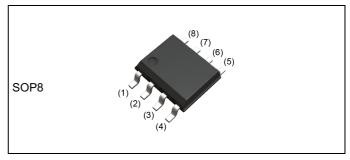
# Features

- 1) Low on resistance
- 2) Small Surface Mount Package (SOP8)
- 3) Pb-free lead plating; RoHS compliant
- 4) Halogen Free

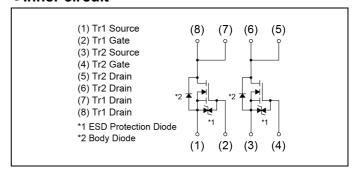
# Application

Switching

### Outline



## Inner circuit



# Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	12
	Basic ordering unit (pcs)	2500
	Taping code	ТВ
	Marking	SH8K51

# ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified) < Tr1 and Tr2>

Parameter	Symbol	Value	Unit	
Drain - Source voltage	$V_{DSS}$	35	V	
Continuous drain current	I <sub>D</sub>	±4.0	А	
Pulsed drain current	I <sub>DP</sub> *1	±16	А	
Gate - Source voltage	$V_{GSS}$	±20	V	
Device discipation (total)	$P_{D}^{*2}$	2.0	W	
Power dissipation (total)	P <sub>D</sub> *3	1.4		
Junction temperature	T <sub>j</sub>	150	°C	
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C	

## ●Thermal resistance

Downwater	Cymah al	Values			1.1:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal registeres innetion, embient (total)	R <sub>thJA</sub> *2	-	-	62.5	°C/W
Thermal resistance, junction - ambient (total)	R <sub>thJA</sub> *3	-	-	89.2	C/VV

# ● Electrical characteristics (T<sub>a</sub> = 25°C) < Tr1 and Tr2>

Damanatan	0	0	Values			l limit
Parameter Symbol Conditions		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_D = 1mA$		-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$			37.3	-	mV/°C
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 35V, V <sub>GS</sub> = 0V		-	1	μА
Gate - Source leakage current	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V		-	±10	μА
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA	1.2	-	2.8	V
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-3.8	-	mV/°C
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 4.0A	-	42	58	
Static drain - source on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 4.0A	-	60	84	mΩ
on - state resistance		V <sub>GS</sub> = 4.0V, I <sub>D</sub> = 4.0A	-	70	98	
Gate resistance	$R_{G}$	f = 1MHz, open drain	-	6.3	-	Ω
Forward Transfer Admittance	Y <sub>fs</sub>  *4	V <sub>DS</sub> = 10V, I <sub>D</sub> = 4.0A	2.5	-	-	S

<sup>\*1</sup> Pw  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

<sup>\*2</sup> Mounted on a ceramic board (30×30×0.8mm)

<sup>\*3</sup> Mounted on a FR4 (25×25×0.8mm)

<sup>\*4</sup> Pulsed

# ●Electrical characteristics (T<sub>a</sub> = 25°C) <Tr1 and Tr2>

Parameter	Cumbal	Conditions	Values			Unit
Parameter	Symbol Conditions —		Min.	Тур.	Max.	Offic
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	300	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 10V	-	85	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	40	-	
Turn - on delay time	t <sub>d(on)</sub> *4	V <sub>DD</sub> ≃ 15V,V <sub>GS</sub> = 10V	-	7	-	
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 2.0A	-	6	-	no
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L = 7.5\Omega$		23		ns
Fall time	t <sub>f</sub> *4	$R_G = 10\Omega$	-	5	-	

# ullet Gate charge characteristics (T<sub>a</sub> = 25°C) <Tr1 and Tr2>

Parameter	Symbol Conditions		Values			Unit
raianietei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	$Q_g^{*4}$		-	4.0	5.6	
Gate - Source charge	Q <sub>gs</sub> *4	$V_{DD} \approx 15V, I_{D} = 4.0A$ $V_{GS} = 5V$	-	1.6	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4	* Go	-	1.5	-	

# ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

## <Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			Unit	
raianetei	Symbol	Conditions	Min.	Тур.	Max.	Uill	
Continuous forward current	I <sub>S</sub>	T - 25°C	-	-	1.6	Δ.	
Pulse forward current	I <sub>SP</sub> *1	T <sub>a</sub> = 25°C	-	-	16	Α	
Forward voltage	V <sub>SD</sub> *4	V <sub>GS</sub> = 0V, I <sub>S</sub> = 4.0A	-	-	1.2	V	

Fig.1 Power Dissipation Derating Curve

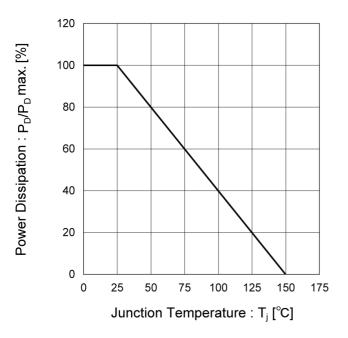
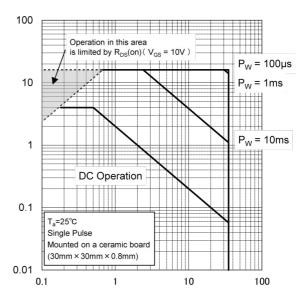


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage: V<sub>DS</sub>[V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

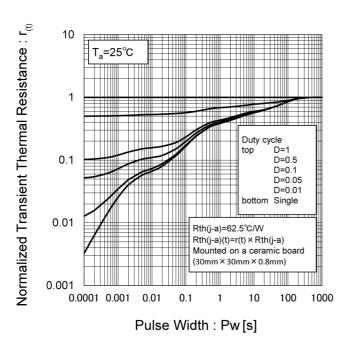
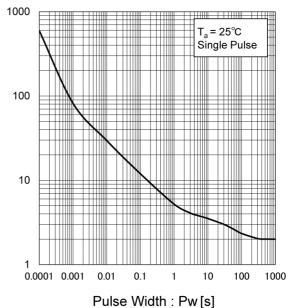


Fig.4 Single Pulse Maximum Power dissipation



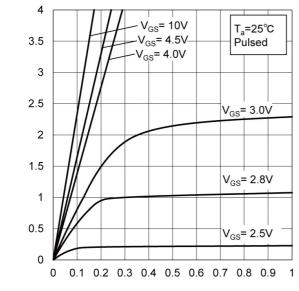
i dise width. i w[s]

Peak Transient Power : P(W)

Drain Current : I<sub>D</sub> [A]

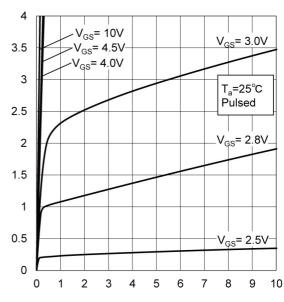
### • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.6 Typical Output Characteristics(II)



Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.7 Breakdown Voltage vs.
Junction Temperature

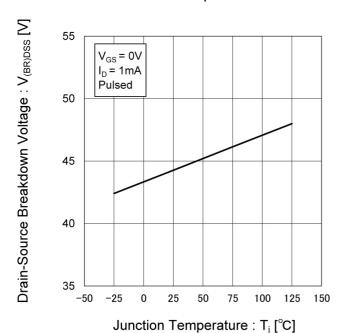


Fig.8 Typical Transfer Characteristics

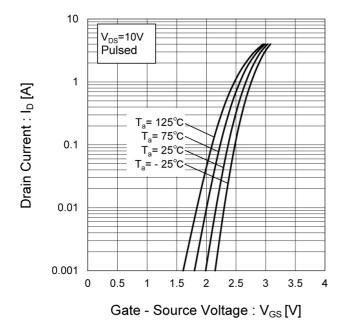


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

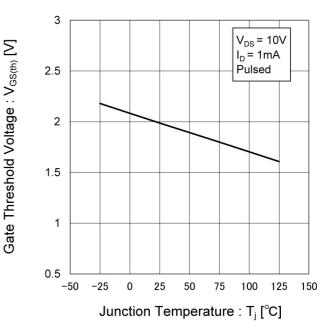


Fig.10 Drain Current Derating Curve

120 100 Drain Current Dissipation 80 : I<sub>D</sub>/I<sub>D</sub>max. [%] 60 40 20 0 -25 0 25 50 75 100 125 150 Junction Temperature : T<sub>j</sub> [°C]

Fig.11 Static Drain - Source On - State Resistance vs. Gate Source Voltage

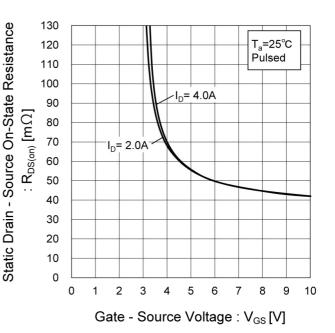
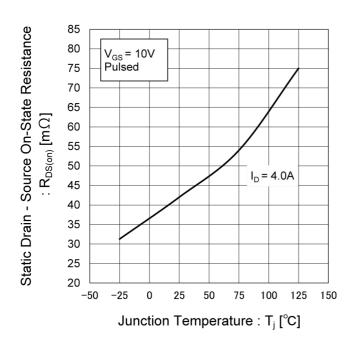


Fig.12 Static Drain - Source On - State Resistance vs. Junction Temperature



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Fig.13 Static Drain - Source On - State Resistance vs. Drain Current (I)

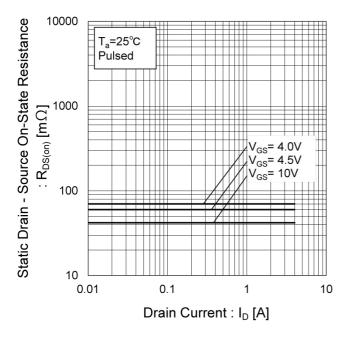


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (II)

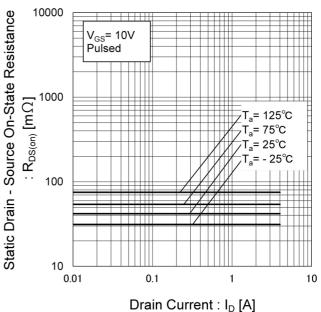


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (III)

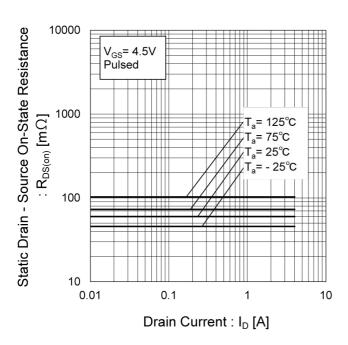


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (IV)

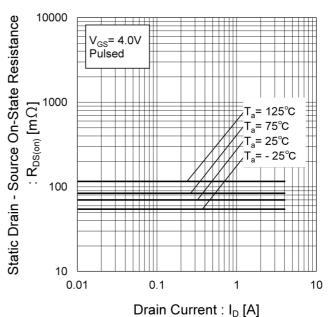


Fig.17 Typical Capacitance vs.

Drain - Source Voltage

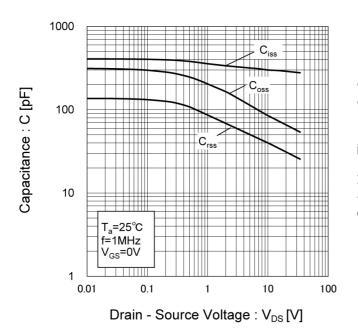


Fig.18 Switching Characteristics

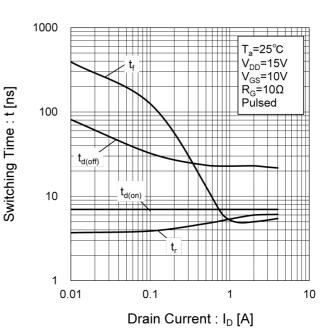


Fig.19 Dynamic Input Characteristics

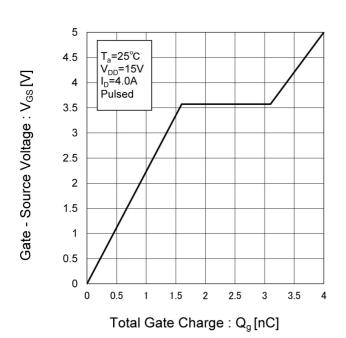
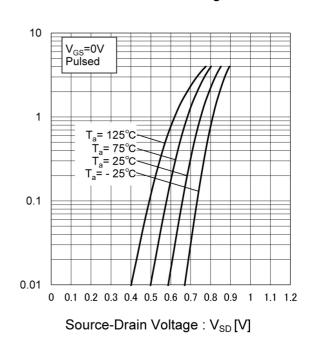


Fig.20 Source Current vs.

Source Drain Voltage



Source Current : Is [A]

## • Measurement circuits < It is the same for the Tr1 and Tr2>

Fig.1-1 Switching Time Measurement Circuit

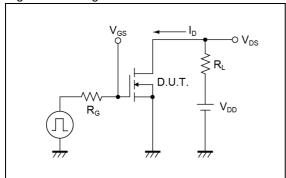


Fig.2-1 Gate Charge Measurement Circuit

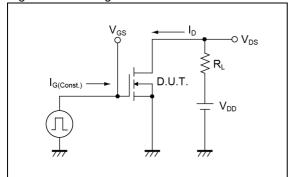


Fig.1-2 Switching Waveforms

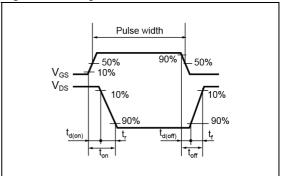
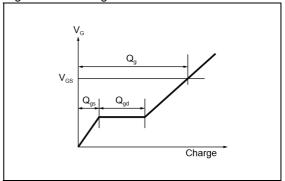
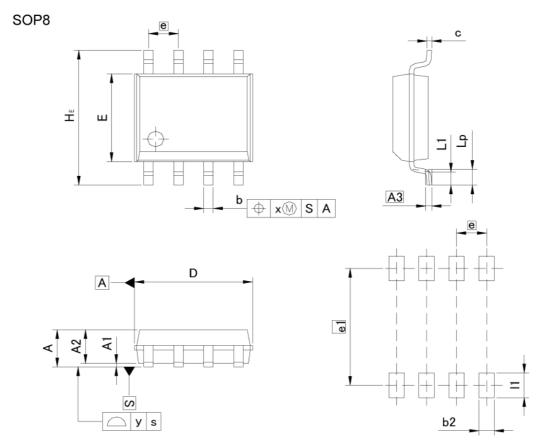


Fig.2-2 Gate Charge Waveform



# Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	-	1.75	-	0.069
A1	0.	15	0.0	06
A2	1.40	1.60	0.055	0.063
A3	0.5	25	0.0	10
b	0.30	0.50	0.012	0.020
С	0.10	0.30	0.004	0.012
D	4.80	5.20	0.189	0.205
E	3.75	4.05	0.148	0.159
е	1,3	27	0.050	
HE	5.70	6.30	0.224	0.248
L1	0.40	0.60	0.016	0.024
Lp	0.65	0.85	0.026	0.033
х	0.15		0.006	
У	0.10		0.0	04
DIM	MILIM	ETERS	INC	HES

DIM	MILIMETERS		INCHES		
DIW	MIN	MAX	MIN	MAX	
b2	-	0.65	-	0.026	
e1	5.	15	0.2	03	
l1	-,7	1.15	- 1	0.045	

Dimension in mm/inches



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CLASSIV	CLASSIII	CLASSⅢ	CLASSⅢ

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  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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